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October 2013

FGB3236_F085 / FGI3236_F085

EcoSPARK^a 320mJ, 360V, N-Channel Ignition IGBT

Features

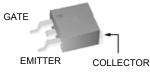
- Industry Standard D²-Pak package
- SCIS Energy = 320mJ at T_J = 25°C
- Logic Level Gate Drive
- Qualified to AEC Q101
- RoHS Compliant

Applications

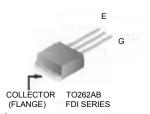
- Automotive Ignition Coil Driver Circuits
- Coil On Plug Applications



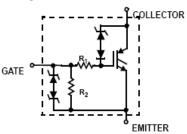
Package



JEDEC TO-263AB D²-Pak



Symbol



Device Maximum Ratings $T_A = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
BV _{CER}	Collector to Emitter Breakdown Voltage (I _C = 1mA)	360	V
BV _{ECS}	Emitter to Collector Voltage - Reverse Battery Condition (I _C = 10mA)	24	V
E _{SCIS25}	Self Clamping Inductive Switching Energy ($I_{SCIS} = 14.7A, L = 3.0 \text{mHy}, T_J = 25^{\circ}\text{C}$)	320	mJ
E _{SCIS150}	Self Clamping Inductive Switching Energy ($I_{SCIS} = 10.4A$, L = 3.0mHy, $T_{J} = 150$ °C)	160	mJ
I _{C25}	Collector Current Continuous, at V _{GE} = 4.0V, T _C = 25°C		Α
I _{C110}	Collector Current Continuous, at V _{GE} = 4.0V, T _C = 110°C		Α
V_{GEM}	Gate to Emitter Voltage Continuous	±10	V
D	Power Dissipation Total, at T _C = 25°C	187	W
P_D	Power Dissipation Derating, for T _C > 25°C	1.25	W/°C
T _J	Operating Junction Temperature Range	-40 to +175	°C
T _{STG}	Storage Junction Temperature Range	-40 to +175	°C
T _L			°C
T _{PKG}	Max. Lead Temp. for Soldering (Package Body for 10s)	260	°C
ESD	Electrostatic Discharge Voltage at 100 pF, 1500 Ω	4	kV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FGB3236	FGB3236_F085	TO263	330mm	24mm	800 units
FGI3236	FGI3236_F085	TO262	Tube	NA	50 units

Electrical Characteristics $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
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Off State Characteristics

BV _{CER}	Collector to Emitter Breakdown Voltage	$I_{CE} = 2\text{mA}, V_{GE} = 0,$ $R_{GE} = 1\text{K}\Omega, \text{ See Fig. 15}$ $T_J = -40 \text{ to } 150^{\circ}\text{C}$		330	363	390	٧
BV _{CES}	Collector to Emitter Breakdown Voltage	$I_{CE} = 10$ mA, $V_{GE} = 0$ V, $R_{GE} = 0$, $T_{J} = -40$ to 150 °C		350	378	410	V
BV _{ECS}	Emitter to Collector Breakdown Voltage	$I_{CE} = -75 \text{mA}, V_{GE} = 0 \text{V},$ $T_{C} = 25 ^{\circ}\text{C}$		30	-	1	V
BV_{GES}	Gate to Emitter Breakdown Voltage	I _{GES} = ±2mA		±12	±14	-	V
1	Collector to Emitter Leakage Current	V _{CES} = 250V,	$T_{\rm C} = 25^{\rm o}{\rm C}$	ı	ı	25	μΑ
ICES	Collector to Emitter Leakage Current	See Fig. 11	$T_{\rm C} = 150^{\rm o}{\rm C}$	-	-	1	mA
1	Emitter to Collector Leakage Current	V _{EC} = 24V,	$T_C = 25^{\circ}C$	-	-	1	mA
I _{ECS}	Emilier to Collector Leakage Current	See Fig.11	$T_{\rm C} = 150^{\rm o}{\rm C}$	-	-	40	IIIA
R ₁	Series Gate Resistance			-	100	-	Ω
R ₂	Gate to Emitter Resistance			10K	-	30K	Ω

On State Characteristics

V _{CE(SAT)}	Collector to Emitter Saturation Voltage	I _{CE} = 6A, V _{GE} = 4V,	T _C =25°C, See Fig. 3	1	1.14	1.4	V
V _{CE(SAT)}	Collector to Emitter Saturation Voltage	I _{CE} = 10A, V _{GE} = 4.5V,	T _C = 150°C, See Fig. 4	-	1.32	1.7	V
V _{CE(SAT)}	Collector to Emitter Saturation Voltage	$I_{CE} = 15A, V_{GE} = 4.5V,$	$T_{\rm C} = 150^{\rm o}{\rm C}$	-	1.61	2.05	V
I _{CE(ON)}	Collector to Emitter On State Current	V_{GE} = 5V, V_{CE} = 5V		50	-	-	Α

Max Units

Min

Electrical Characteristics $T_A = 25^{\circ}C$ unless otherwise noted

Parameter

Dynamic Characteristics								
Q _{G(ON)}	Gate Charge	I _{CE} = 10A, V _{CE} = 12V, V _{GE} = 5V, See Fig.14		-	20	-	nC	
V	Gate to Emitter Threshold Voltage	I_{CE} = 1mA, V_{CE} = V_{GE} ,	$T_C = 25^{\circ}C$	1.3	1.6	2.2	V	
V _{GE(TH)} G	Cate to Emitter Threshold Voltage	See Fig. 10	$T_{\rm C} = 150^{\rm o}{\rm C}$	0.75	1.1	1.8	\ \ \	
V_{GEP}	Gate to Emitter Plateau Voltage	V _{CE} = 12V, I _{CE} = 10A		-	2.6	-	V	

Test Conditions

Switching Characteristics

Symbol

t _{d(ON)R}	Current Turn-On Delay Time-Resistive		-	0.65	4	μS
t _{rR}	Current Rise Time-Resistive	$V_{GE} = 5V, R_G = 1K\Omega$ $T_J = 25^{\circ}C, See Fig.12$	-	1.7	7	μS
t _{d(OFF)L}		$V_{CE} = 300V, L = 500 \mu Hy,$	-	5.4	15	μS
t_{fL}	Current Fall Time-Inductive	V_{GE} = 5V, R_G = 1K Ω T_J = 25°C, See Fig.12	-	1.64	15	μS
SCIS	Self Clamped inductive Switching	$T_J = 25^{\circ}\text{C}$, L = 3.0mHy, $I_{CE} = 14.7\text{A}$, $R_G = 1\text{K}\Omega$, $V_{GE} = 5\text{V}$, See Fig.1&2	-	-	320	mJ

Thermal Characteristics

$R_{\theta JC}$ Th	hermal Resistance Junction to Case	All Packages	1	1	0.8	°C/W
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Typical Performance Curves

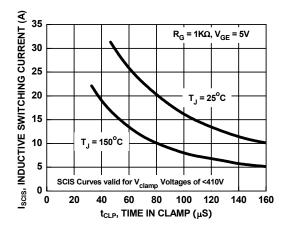


Figure 1. Self Clamped Inductive Switching Current vs. Time in Clamp

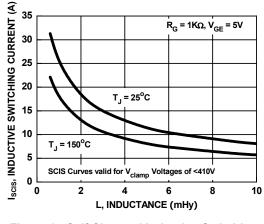


Figure 2. Self Clamped Inductive Switching Current vs. Inductance

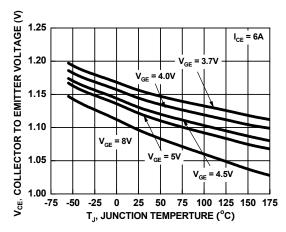


Figure 3. Collector to Emitter On-State Voltage vs. Junction Temperature

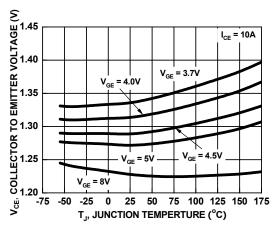


Figure 4. Collector to Emitter On-State Voltage vs. Junction Temperature

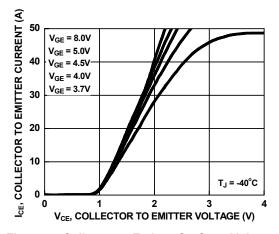


Figure 5. Collector to Emitter On-State Voltage vs. Collector Current

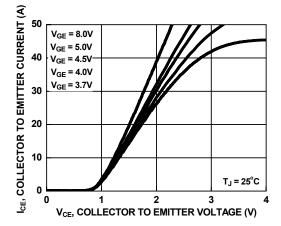


Figure 6. Collector to Emitter On-State Voltage vs. Collector Current

Typical Performance Curves (Continued)

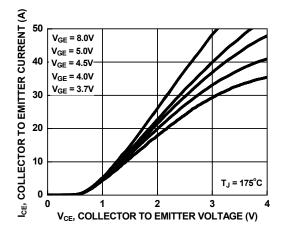


Figure 7. Collector to Emitter On-State Voltage vs. Collector Current

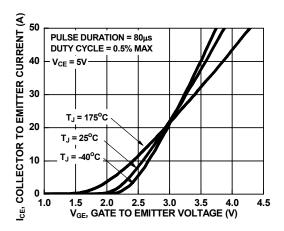


Figure 8. Transfer Characteristics

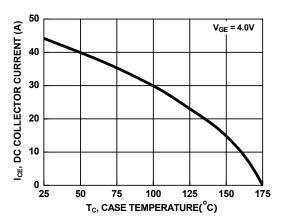


Figure 9. DC Collector Current vs. Case Temperature

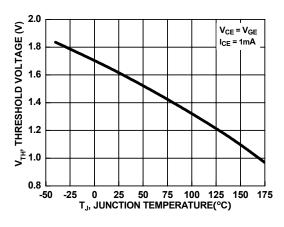


Figure 10. Threshold Voltage vs. Junction Temperature

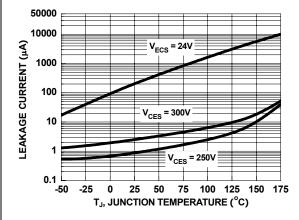


Figure 11. Leakage Current vs. Junction Temperature

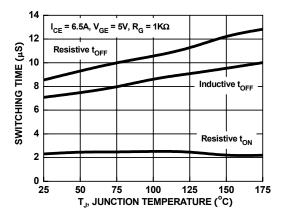
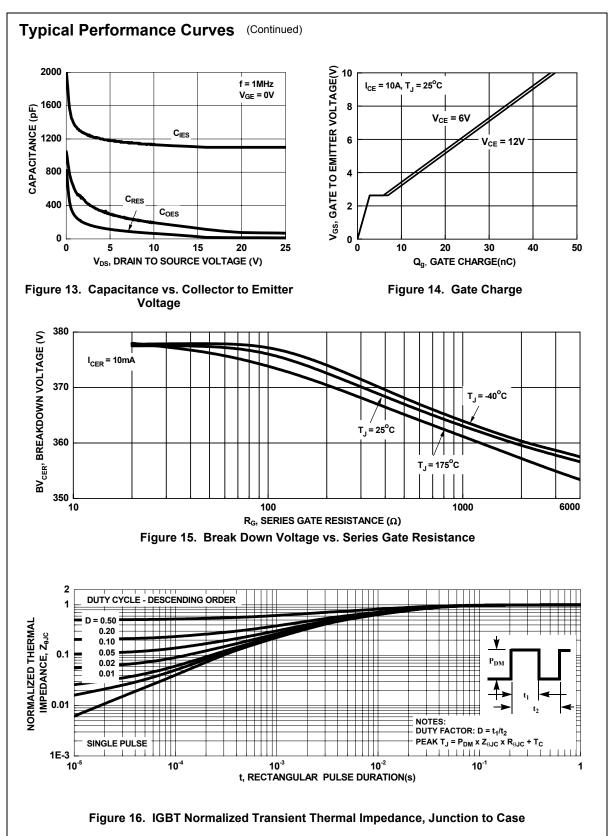


Figure 12. Switching Time vs. Junction Temperature



Test Circuit and Waveforms

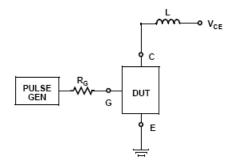


Figure 17. Inductive Switching Test Circuit

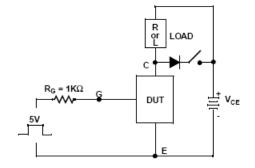


Figure 18. t_{ON} and t_{OFF} Switching Test Circuit

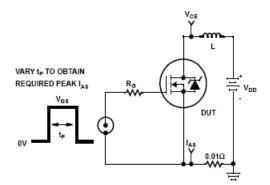


Figure 19. Energy Test Circuit

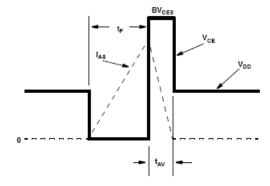
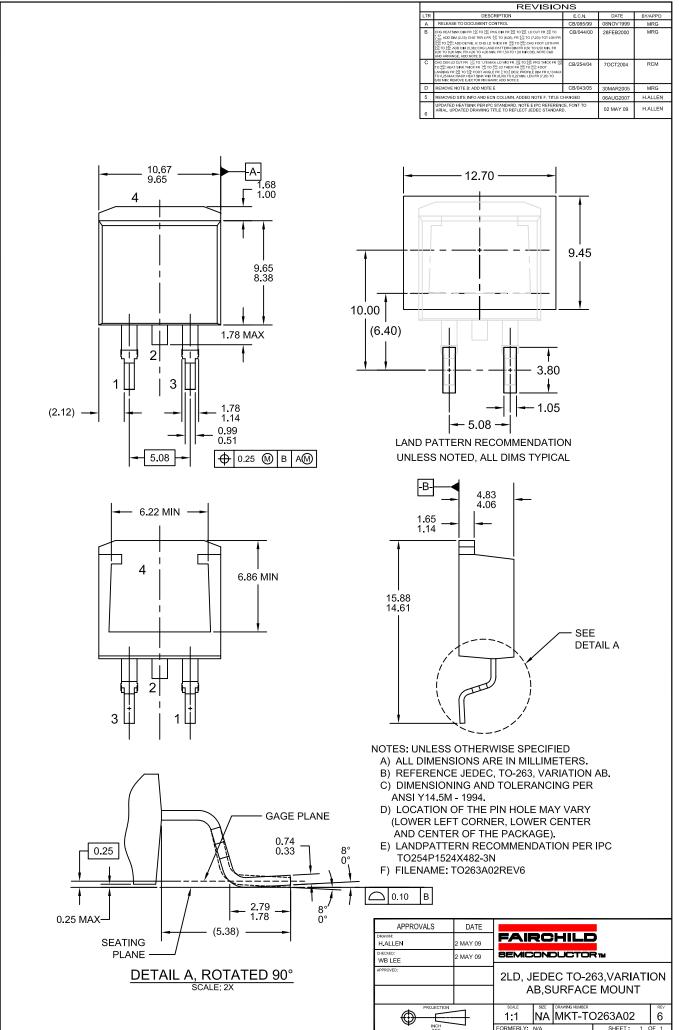
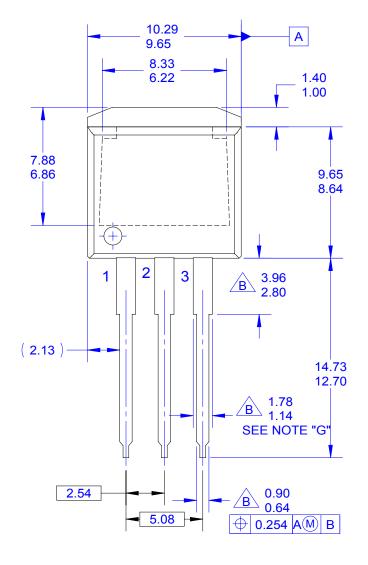
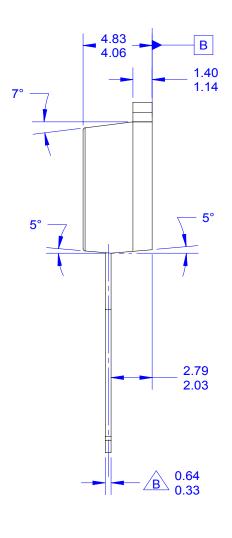


Figure 20. Energy Waveforms



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- A. EXCEPT WHERE NOTED CONFORMS TO
 TO262 JEDEC VARIATION AA.
 B DOES NOT COMPLY JEDEC STD. VALUE.
 C. ALL DIMENSIONS ARE IN MILLIMETERS.
 D. DIMENSIONS ARE EXCLUSIVE OF BURRS,
 MOLD FLASH AND TIE BAR PROTRUSIONS.
 E. DIMENSION AND TOLERANCE AS PER ANSI
 Y14 5-1904
- F. LOCATION OF PIN HOLE MAY VARY
 (LOWER LEFT CORNER, LOWER CENTER
 AND CENTER OF PACKAGE)
 G. MAXIMUM WIDTH FOR F102 DEVICE = 1.35 MAX.
- H. DRAWING FILE NAME: TO262A03REV5

APPROVALS	DATE				_	
DRAWN: BOBOY MALDO	11FEB2010	F/	AIR	CHILE		
CHECKED: KH LEE		8E	MICO	NDUCTO	Rтм	
APPROVED: BY HUANG		TO262 3LD JEDEC				
APPROVED: HOWARD ALLEN		VARIATION AA				
PROJECTION		SCALE SIZE DRAWING NUMBER 1:1 N/A MKT-TO262A0				FEV 5
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Current Transfer Logic™



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Dennicion of Terms		
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